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Should be replaced with:

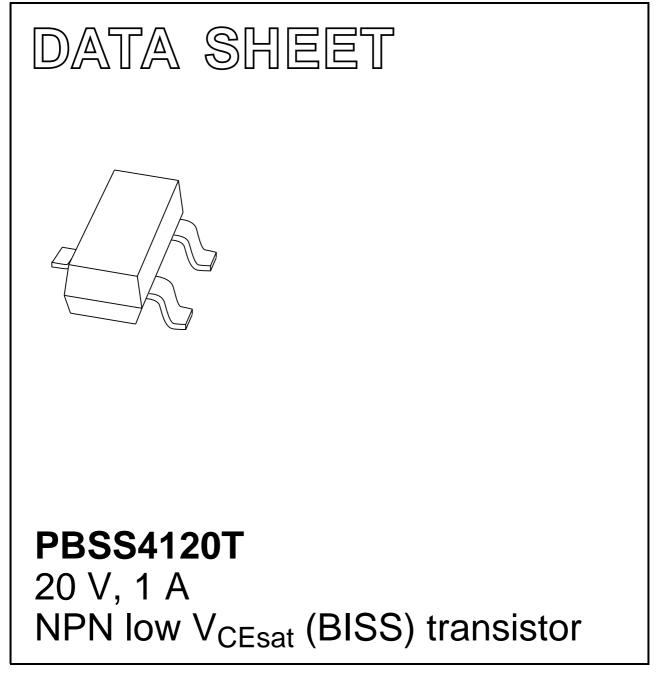
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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS



Product data sheet

2003 Sep 29



20 V, 1 A NPN low V_{CEsat} (BISS) transistor

FEATURES

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High efficiency leading to less heat generation
- · Reduced printed-circuit board requirements
- Cost effective alternative to MOSFETs in specific applications.

APPLICATIONS

- Power management
 - DC/DC conversion
 - Supply line switching
 - Battery charger
 - LCD backlighting.
- Peripheral driver
 - Driver in low supply voltage applications (e.g. lamps and LEDs)
 - Inductive load drivers (e.g. relays, buzzers and motors).

DESCRIPTION

NPN BISS transistor in a SOT23 plastic package providing ultra low V_{CEsat} and R_{CEsat} parameters. PNP complement: PBSS5120T.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾	
PBSS4120T	*3B	

Note

- 1. * = p: made in Hong Kong.
- * = t: made in Malaysia.
 - * = W: made in China.

ORDERING INFORMATION

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT	
V _{CEO}	collector-emitter voltage	20	V	
I _C	collector current (DC)	1	А	
I _{CM}	peak collector current	3	А	
R _{CEsat}	equivalent on-resistance	200	mΩ	

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	

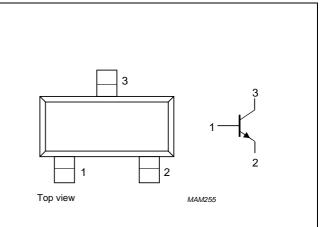


Fig.1 Simplified outline (SOT23) and symbol.

TYPE NUMBER		PACKAGE		
ITFE NUMBER	NAME DESCRIPTION		VERSION	
PBSS4120T	 plastic surface mounted package; 3 leads 		SOT23	

PBSS4120T

PBSS4120T

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	30	V
V _{CEO}	collector-emitter voltage	open base	-	20	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current (DC)		-	1	А
I _{CM}	peak collector current		-	3	А
I _{BM}	peak base current		-	300	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C; note 1$	-	300	mW
		$T_{amb} \le 25 \ ^{\circ}C; note 2$	-	480	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Device mounted on a FR4 printed-circuit board, single-sided copper, tinplated, standard footprint.
- 2. Device mounted on a FR4 printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	in free air; note 1	417	K/W
		in free air; note 2	260	K/W

Notes

- 1. Device mounted on a FR4 printed-circuit board, single-sided copper, tinplated, standard footprint.
- 2. Device mounted on a FR4 printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².

PBSS4120T

CHARACTERISTICS

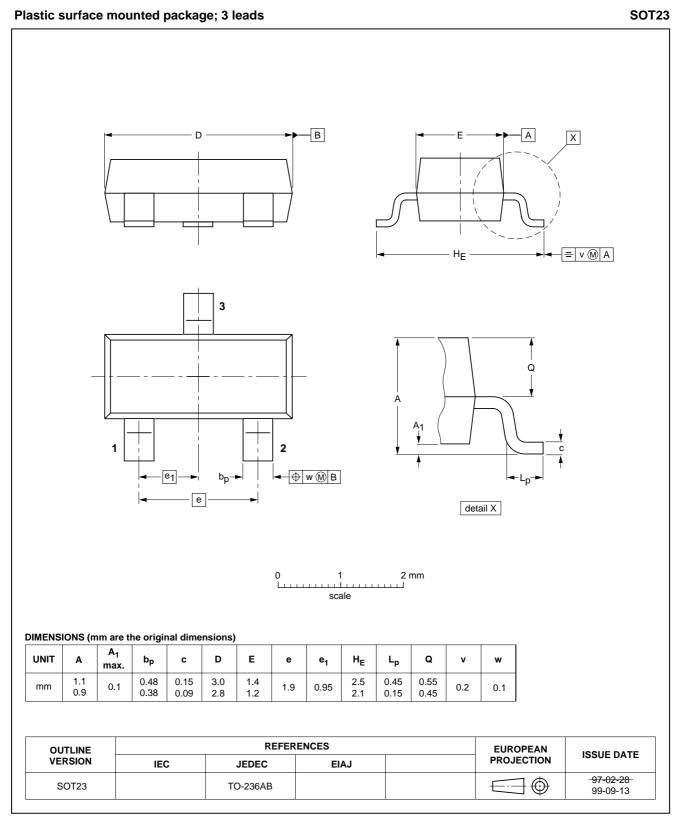
 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = 30 \text{ V}; I_E = 0$	-	_	100	nA
		$V_{CB} = 30 \text{ V}; I_E = 0; T_j = 150 ^{\circ}\text{C}$	_	_	50	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 4 \text{ V}; I_{C} = 0$	_	_	100	nA
h _{FE}	DC current gain	$V_{CE} = 2 \text{ V}; \text{ I}_{C} = 100 \text{ mA}$	350	470	-	
		$V_{CE} = 2 \text{ V}; \text{ I}_{C} = 500 \text{ mA}$	300	450	_	
		V _{CE} = 2 V; I _C = 1 A	280	420	_	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = 100 \text{ mA}; I_{\rm B} = 1 \text{ mA}$	_	_	80	mV
		I _C = 500 mA; I _B = 50 mA	_	_	110	mV
		I _C = 750 mA; I _B = 15 mA	_	_	200	mV
		I _C = 1 A; I _B = 50 mA; note 1	_	_	250	mV
R _{CEsat}	equivalent on-resistance	$I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}; \text{ note } 1$	_	_	220	mΩ
V _{BEsat}	base-emitter saturation voltage	I _C = 1 A; I _B = 100 mA; note 1	_	_	1.1	V
V _{BEon}	base-emitter turn-on voltage	$V_{CE} = 2 \text{ V}; \text{ I}_{C} = 100 \text{ mA}$	_	_	0.75	V
f _T	transition frequency	$I_{C} = 100 \text{ mA}; V_{CE} = 10 \text{ V};$ f = 100 MHz	100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0;$ f = 1 MHz	-	_	20	pF

Note

1. Pulse test: $t_p \leq 300~\mu\text{s};~\delta \leq 0.02.$

PACKAGE OUTLINE



PBSS4120T

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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NXP Semiconductors

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Contact information

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Printed in The Netherlands

R75/01/pp7

Date of release: 2003 Sep 29

Document order number: 9397 750 11896

